

SSC8029GQ4

P-Channel Enhancement Mode MOSFET

Features

VDS	VGS	RDSON Typ.	ID
		17mR@-4V5	
-20V	±12V	21mR@-2V5	-15A
		26mR@-1V8	

> Description

This device is produced with high cell density DMOS trench technology, which is especially used to minimize on-state resistance. This device is particularly suited for low voltage power management requiring a wild range of given voltage ratings(4.5V~18V) such as load switch and battery protection.

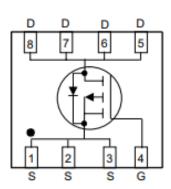
- > Applications
- Load Switch
- NB battery
- DCDC conversion

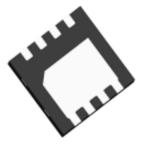
> Ordering Information

Device	Package	Shipping
SSC8029GQ4	DFN3x3	5000/Reel

Pin configuration

Top view





Bottom View



(Y: year/W: week) Marking



> Absolute Maximum Ratings(T_A=25[°]C unless otherwise noted)

Symbol	Parameter	Ratings	Unit
V _{DSS}	Drain-to-Source Voltage	-20	V
V _{GSS}	Gate-to-Source Voltage	±12	V
ID	Continuous Drain Current ^a	-15	А
I _{DM}	Pulsed Drain Current ^b	-45	А
PD	Power Dissipation ^c	15	W
P _{DSM}	Power Dissipation ^a	2.5	W
TJ	Operation junction temperature	-55 to 150	°C
Т _{stg}	Storage temperature range	-55 to 150	°C

> Thermal Resistance Ratings($T_A=25^{\circ}C$ unless otherwise noted)

Symbol	bol Parameter		Maximum	Unit
$R_{ heta JA}$	Junction-to-Ambient Thermal Resistance ^a		60	°C 1.M
R _{θJC}	Junction-to-Case Thermal Resistance		9	°C/W

Note:

- a. The value of R_{BJA} is measured with the device mounted on 1 in² FR-4 board with 2oz.copper,in a still air environment with T_A=25°C. The value in any given application depends on the user is specific board design. The current rating is based on the t ≤ 10s thermal resistance rating.
- b. Repetitive rating, pulse width limited by junction temperature.
- c. The power dissipation P_D is based on T_{J(MAX)}=150°C, using junction-to-case thermal resistance, and is more useful in setting the upper dissipation limit for cases where additional heat sinking is used.

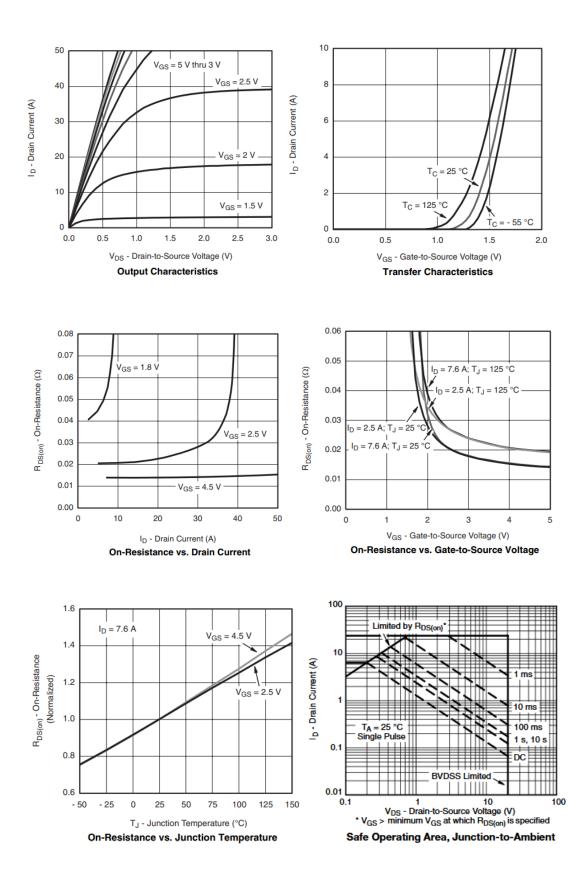


\succ Electronics Characteristics(T_A=25 °C unless otherwise noted)

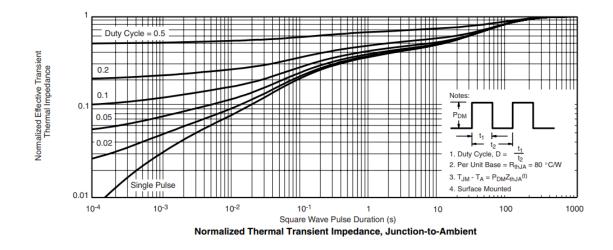
Symbol	Parameter	Test Conditions	Min	Тур.	Мах	Unit	
V _{(BR)DSS}	Drain-Source Breakdown Voltage	VGS=0V, ID=-250uA	-20			V	
$V_{GS \ (th)}$	Gate Threshold Voltage	VDS=VGS, ID=-250uA	-0.5	-0.6	-1	V	
	Ducia Occurre Oc	VGS=-4.5V, ID=-5.5A		17	22	mR	
R _{DS(on)}	Drain-Source On- Resistance	VGS=-2.5V, ID=-2.5A		21	27		
	Resistance	VGS=-1.8V, ID=-1.8A		26	50		
I _{DSS}	Zero Gate Voltage Drain Current	VDS=-20V, VGS=0V			-1	uA	
I _{GSS}	Gate-Source leak current	VGS=±12V, VDS=0V			±100	nA	
G _{FS}	Transconductance	VDS=-5V, ID=-10A		25		S	
V _{SD}	Forward Voltage	VGS=0V,IS=-1A		-0.75	-1.3	V	
Ciss	Input Capacitance			1828			
Coss	Output Capacitance	VDS=-10V, VGS=0V, f=1MHz		203		pF	
Crss	Reverse Transfer Capacitance			201			
T _{D(ON)}	Turn-on delay time			16			
Tr	Rise time	VGS=-4.5V,		14			
T _{D(OFF)}	Turn-off delay time	VDS=-10V, RL=6R, RG=6R, ID=-6.5A		78		ns	
Tf	Fall time			66			



> Typical Characteristics(T_A=25°C unless otherwise noted)

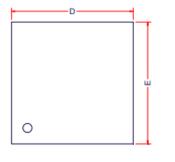




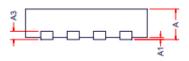




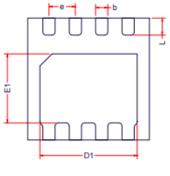
Package Information



TOP VIEW



SIDE VIEW



BOTTOM VIEW

DFN3x3-8L

Sumbal	Dimensions in Millimeters			
Symbol	Min.	Тур.	Max.	
А	0.70	0.75	0.80	
A1	0.00	0.02	0.05	
A2		0.20Ref		
D	2.90	3.00	3.10	
E	2.90	3.00	3.10	
D1	2.35	2.40	2.45	
E1	1.65	1.70	1.75	
b	0.25	0.30	0.35	
е		0.65BSC		
L	0.37	0.42	0.47	



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